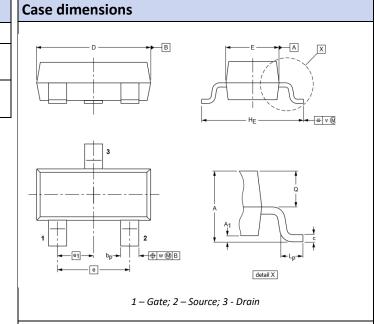


NPN Bipolar Transistor

Primary characteristics						
Symbol	Parameter Value Unit					
lc	Continuous collector current	600	mA			
V _{CEO}	Collector-emitter voltage	160	V			



Features

- **SOT-23** case for easy automatic insertion
- Pb-free and RoHS compliant
- Epitaxial planar die construction

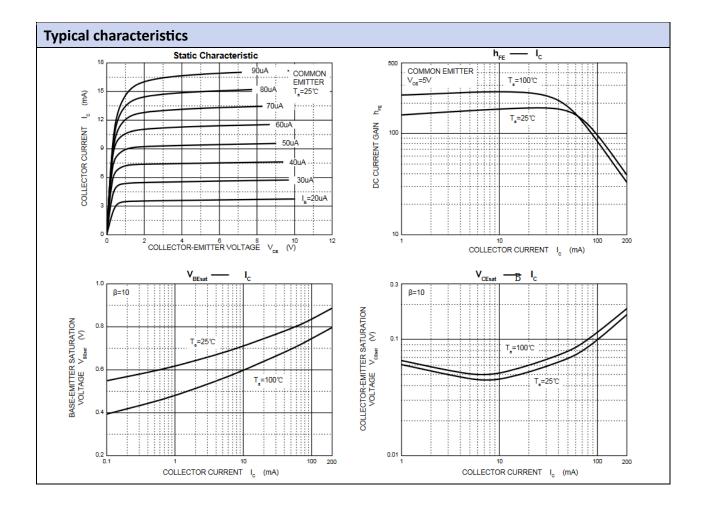
SOT-23 (TO-236AB)													
Unit	Α	A ₁ max	b _p	С	D	Е	е	e1	HE	Lp	ά	v	w
mm	1.0 ±0.1			0.12 ±0.03				0.95			0.5 ±0.05		0.1

Absolute maximum ratings (T _A = 25°C unless otherwise noted)								
Characteristic	Symbol	Value	Unit					
Collector-base voltage	V _{сво}	180	V					
Collector-emitter voltage	Vceo	160	V					
Emitter-base voltage	V _{EBO}	6.0	V					
Continuous collector current	lc	600	mA					
Total power dissipation	PD	300	mW					
Operating junction temperature range	Тı, Тstg	-55 ~ 150	°C					

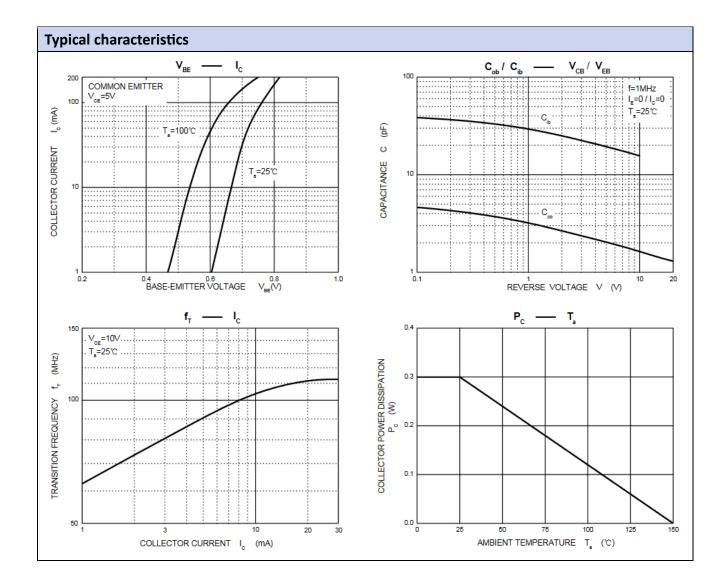


Electrical characteristics (T _A = 25°C)							
Ch ava stavistic	To all an an altain an	Gundhal	Value				
Characteristic	Test condition	Symbol	Min.	Тур.	Max.	Unit	
Collector-base breakdown voltage	I _E =0V, I _C =100μA	V _{(BR)CBO}	180	-	-	V	
Collector-emitter breakdown voltage ¹⁾	I _C =1.0mA, I _B =0V	V _{(BR)CEO}	160	-	-	V	
Emitter-base breakdown voltage	I _E =10μΑ, I _C =0	V _{(BR)EBO}	6.0	-	-	V	
Collector cut-off current	V _{CB} =120V, I _E =0	І _{сво}	-	-	50	nA	
Emitter cut-off current	V _{EB} =4.0V, I _C =0	I _{EBO}	-	-	50	nA	
	V _{CE} =5.0V, I _C =1.0mA	h _{FE(1)}	80	-	-		
DC current gain ¹⁾	V _{CE} =5.0V, I _C =10mA	h _{FE(2)}	100	-	300		
	V _{CE} =5.0V, I _C =50mA	h _{FE(3)}	50	-	-		
Collector-emitter saturation voltage ¹⁾	Ic=50mA, I _B =5.0mA	V _{CE(sat)}	-	-	500	mV	
Base-emitter saturation voltage ¹⁾	I _c =50mA, I _B =5.0mA	V _{BE(sat)}	(sat) 1.0		1.0	V	
Transition frequency	V _{CE} =10V, I _C =10mA, f=100MHz	f⊤	100	-	-	MHz	

¹⁾ Pulse test: pulse width=300µs, duty cycle=2.0%

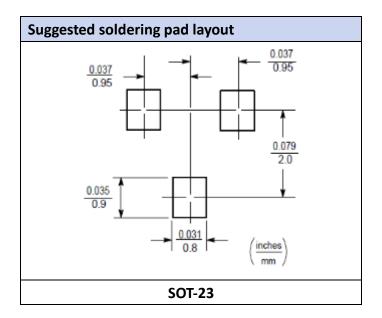












Ordering information				
Part Number	Package	Marking	Shipping Quantity	Dimensions
MMBT5551	SOT-23	G1	3000 pcs / 7"reel	

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